

2N5679 2N5680 PNP
2N5681 2N5682 NPN

**COMPLEMENTARY
SILICON POWER TRANSISTORS**



TO-39 CASE



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DESCRIPTION:

The CENTRAL SEMICONDUCTOR 2N5679, 2N5681 series devices are complementary silicon power transistors, manufactured by the epitaxial planar process, designed for general purpose amplifier and switching applications where high voltages are required.

MARKING: FULL PART NUMBER

MAXIMUM RATINGS: ($T_A=25^\circ\text{C}$ unless otherwise noted)

	SYMBOL	2N5679 2N5681	2N5680 2N5682	UNITS
Collector-Base Voltage	V_{CBO}	100	120	V
Collector-Emitter Voltage	V_{CEO}	100	120	V
Emitter-Base Voltage	V_{EBO}		4.0	V
Continuous Collector Current	I_C		1.0	A
Continuous Base Current	I_B		0.5	A
Power Dissipation	P_D		1.0	W
Power Dissipation ($T_C=25^\circ\text{C}$)	P_D		10	W
Operating and Storage Junction Temperature	T_J, T_{stg}		-65 to +200	$^\circ\text{C}$
Thermal Resistance	θ_{JA}		175	$^\circ\text{C/W}$
Thermal Resistance	θ_{JC}		17.5	$^\circ\text{C/W}$

ELECTRICAL CHARACTERISTICS: ($T_A=25^\circ\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
I_{CBO}	$V_{CB}=\text{Rated } V_{CBO}$		1.0	μA
I_{CEV}	$V_{CE}=\text{Rated } V_{CEO}, V_{EB}=1.5\text{V}$		1.0	μA
I_{CEV}	$V_{CE}=\text{Rated } V_{CEO}, V_{EB}=1.5\text{V}, T_C=150^\circ\text{C}$		1.0	mA
I_{CEO}	$V_{CE}=70\text{V}$ (2N5679, 2N5681)		10	μA
I_{CEO}	$V_{CE}=80\text{V}$ (2N5680, 2N5682)		10	μA
I_{EBO}	$V_{EB}=4.0\text{V}$		1.0	μA
BV_{CEO}	$I_C=10\text{mA}$ (2N5679, 2N5681)	100		V
BV_{CEO}	$I_C=10\text{mA}$ (2N5680, 2N5682)	120		V
$V_{CE(SAT)}$	$I_C=250\text{mA}, I_B=25\text{mA}$		0.6	V
$V_{CE(SAT)}$	$I_C=500\text{mA}, I_B=50\text{mA}$		1.0	V
$V_{CE(SAT)}$	$I_C=1.0\text{A}, I_B=200\text{mA}$		2.0	V
$V_{BE(ON)}$	$V_{CE}=2.0\text{V}, I_C=250\text{mA}$		1.0	V
h_{FE}	$V_{CE}=2.0\text{V}, I_C=250\text{mA}$	40	150	
h_{FE}	$V_{CE}=2.0\text{V}, I_C=1.0\text{A}$	5.0		
h_{fe}	$V_{CE}=1.5\text{V}, I_C=0.2\text{A}, f=1.0\text{kHz}$	40		
f_T	$V_{CE}=10\text{V}, I_C=100\text{mA}, f=10\text{MHz}$	30		MHz
C_{ob}	$V_{CB}=20\text{V}, I_E=0, f=1.0\text{MHz}$		50	pF

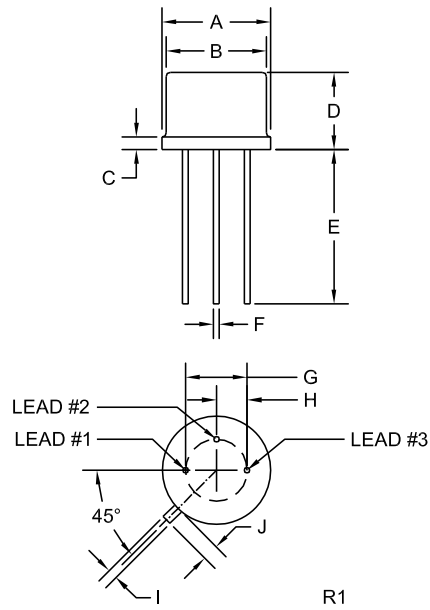
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TO-39 CASE - MECHANICAL OUTLINE



SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A (DIA)	0.335	0.370	8.51	9.40
B (DIA)	0.315	0.335	8.00	8.51
C	-	0.040	-	1.02
D	0.240	0.260	6.10	6.60
E	0.500	-	12.70	-
F (DIA)	0.016	0.021	0.41	0.53
G (DIA)	0.200		5.08	
H	0.100		2.54	
I	0.028	0.034	0.71	0.86
J	0.029	0.045	0.74	1.14

TO-39 (REV: R1)

LEAD CODE:

- 1) Emitter
- 2) Base
- 3) Collector

MARKING: FULL PART NUMBER

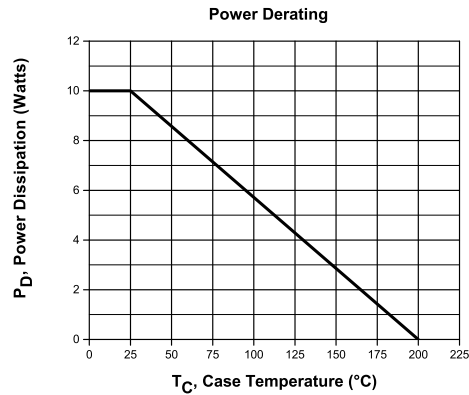
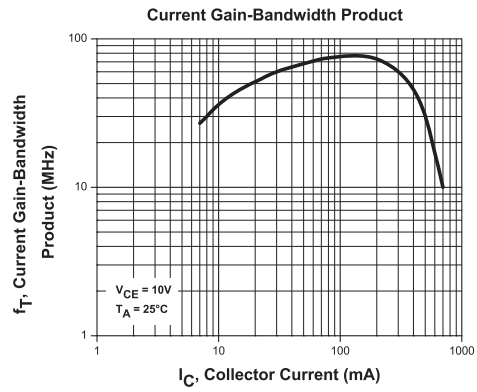
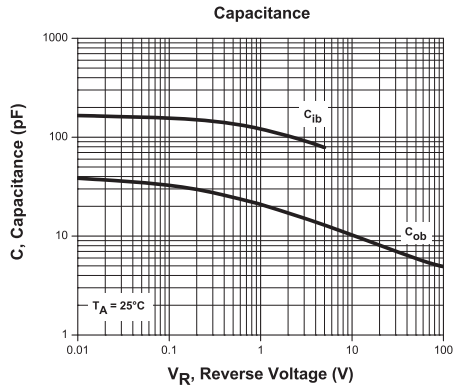
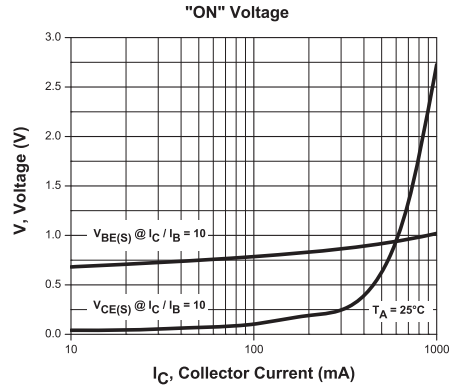
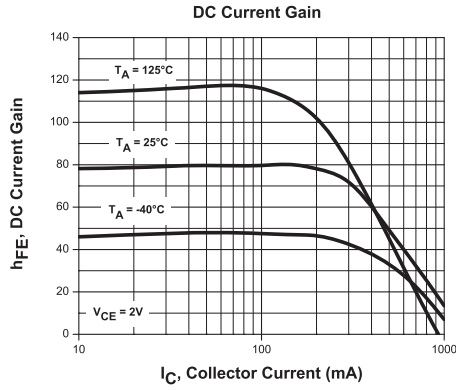
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PNP TYPICAL ELECTRICAL CHARACTERISTICS



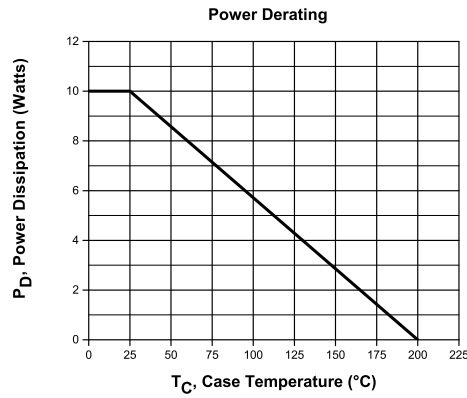
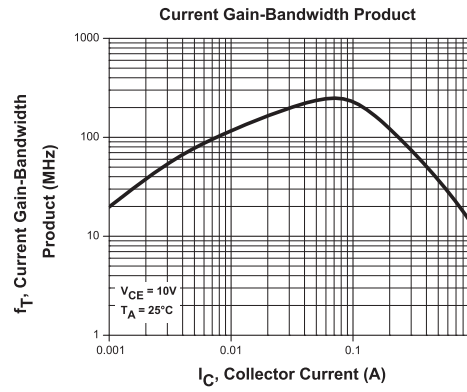
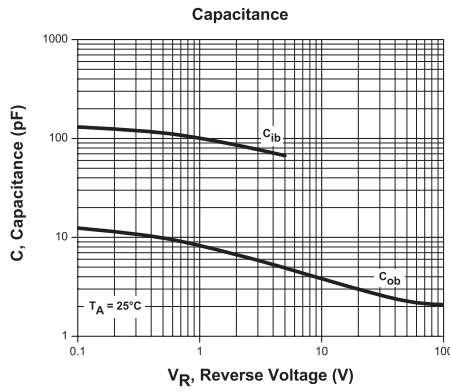
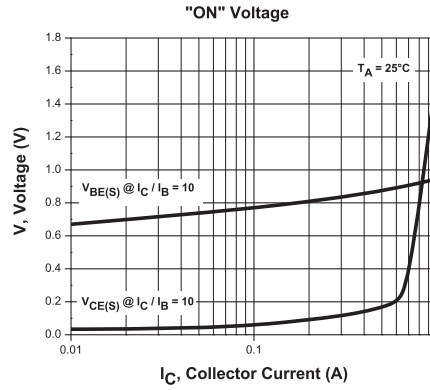
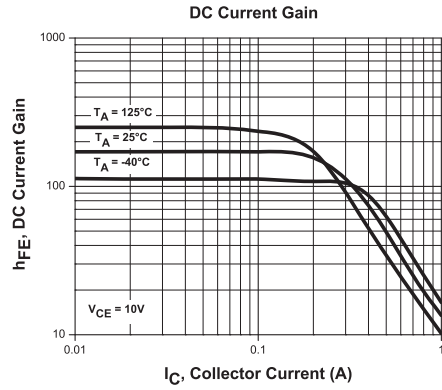
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NPN TYPICAL ELECTRICAL CHARACTERISTICS



R2 (2-December 2013)



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- Custom product packing

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- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- Application and design sample kits
- Custom product and package development

REQUESTING PRODUCT PLATING

1. If requesting Tin/Lead plated devices, add the suffix " TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
2. If requesting Lead (Pb) Free plated devices, add the suffix " PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

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